

International IOR Rectifier

30CTH03

Hyperfast Rectifier

Features

- Hyperfast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature

$$t_{rr} = 36\text{ns max.}$$

$$I_{F(AV)} = 30\text{Amp}$$

$$V_R = 300\text{V}$$

Description/ Applications

International Rectifier's 300V series are the state of the art Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and Hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

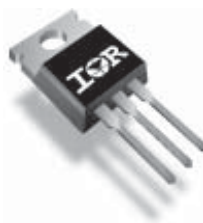
Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

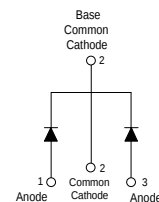
Parameters	Max	Units
V_{RRM} Peak Repetitive Reverse Voltage	300	V
$I_{F(AV)}$ Average Rectified Forward Current @ $T_c = 153^\circ\text{C}$ Per Diode	15	A
Per Device	30	
I_{FSM} Non Repetitive Peak Surge Current @ $T_j = 25^\circ\text{C}$	150	
T_j, T_{STG} Operating Junction and Storage Temperatures	- 65 to 175	$^\circ\text{C}$

Case Styles

30CTH03



TO-220AB



Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V_{BR}, V_r Breakdown Voltage, Blocking Voltage	300	-	-	V	$I_R = 100\mu\text{A}$
V_F Forward Voltage	-	1.0	1.25	V	$I_F = 15\text{A}, T_J = 25^\circ\text{C}$
	-	0.85	0.95	V	$I_F = 15\text{A}, T_J = 125^\circ\text{C}$
I_R Reverse Leakage Current	-	-	40	μA	$V_R = V_R \text{ Rated}$
	-	8	200	μA	$T_J = 125^\circ\text{C}, V_R = V_R \text{ Rated}$
C_T Junction Capacitance	-	38	-	pF	$V_R = 300\text{V}$
L_S Series Inductance	-	8	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ $T_C = 25^\circ\text{C}$ (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t_{rr} Reverse Recovery Time	-	-	36	ns	$I_F = 1\text{A}, di_F/dt = 50\text{A}/\mu\text{s}, V_R = 30\text{V}$
	-	-	30		$I_F = 1\text{A}, di_F/dt = 100\text{A}/\mu\text{s}, V_R = 30\text{V}$
	-	33	-		$T_J = 25^\circ\text{C}$
	-	48	-		$T_J = 125^\circ\text{C}$
I_{RRM} Peak Recovery Current	-	2.8	-	A	$T_J = 25^\circ\text{C}$
	-	6.5	-		$T_J = 125^\circ\text{C}$
Q_{rr} Reverse Recovery Charge	-	46	-	nC	$T_J = 25^\circ\text{C}$
	-	160	-		$T_J = 125^\circ\text{C}$

$I_F = 15\text{A}$
 $di_F/dt = 200\text{A}/\mu\text{s}$
 $V_R = 200\text{V}$

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
T_J Max. Junction Temperature Range	-	-	175	$^\circ\text{C}$
T_{Stg} Max. Storage Temperature Range	- 65	-	175	
R_{thJC} Thermal Resistance, Junction to Case Per Diode	-	-	1.4	$^\circ\text{C}/\text{W}$

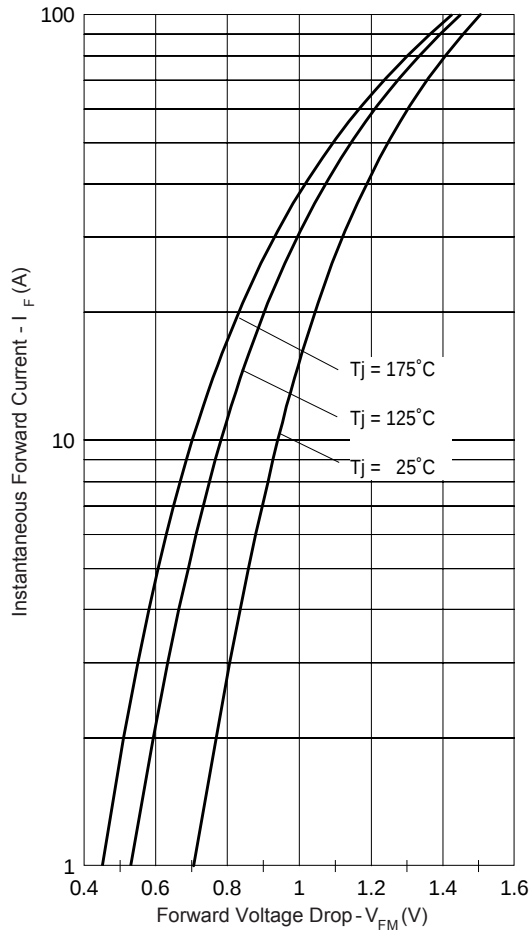


Fig. 1 - Typical Forward Voltage Drop Characteristics

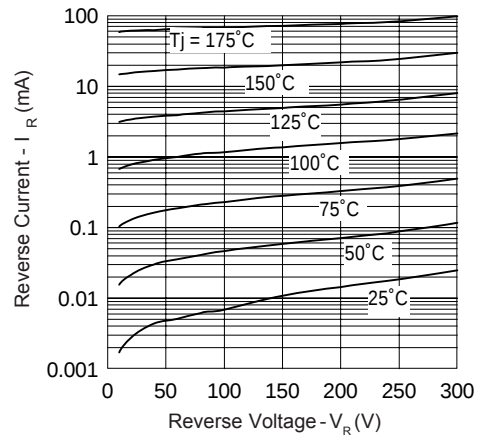


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

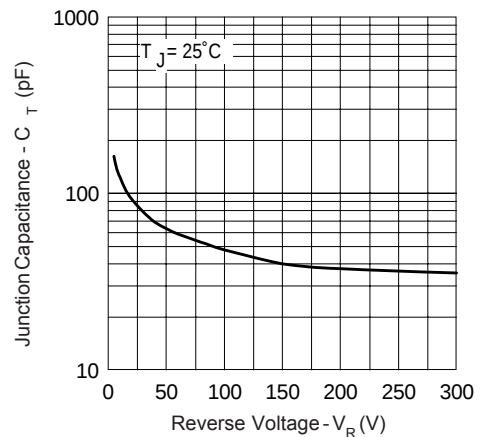


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

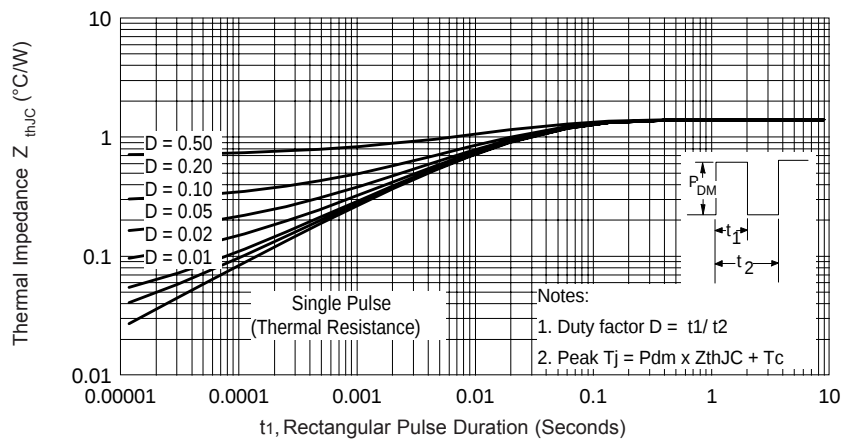


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

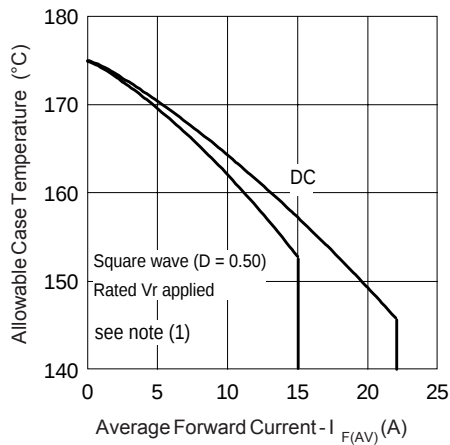


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

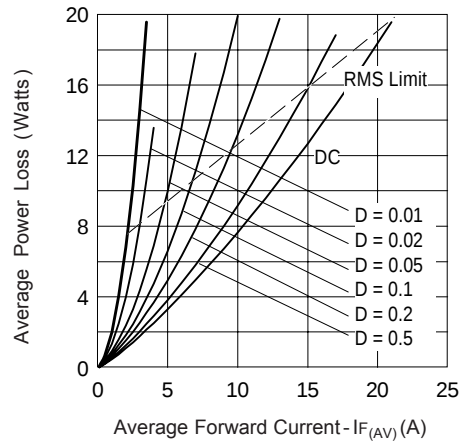


Fig. 6 - Forward Power Loss Characteristics

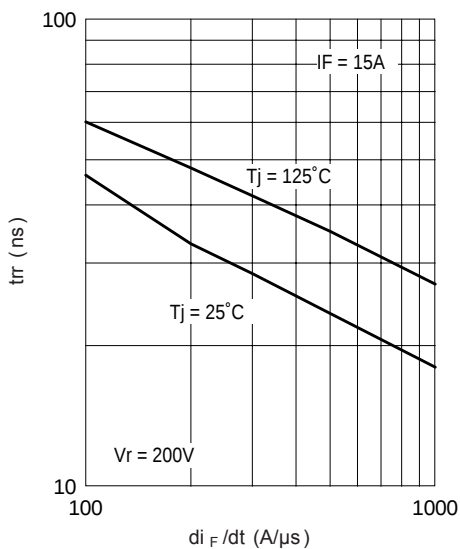


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

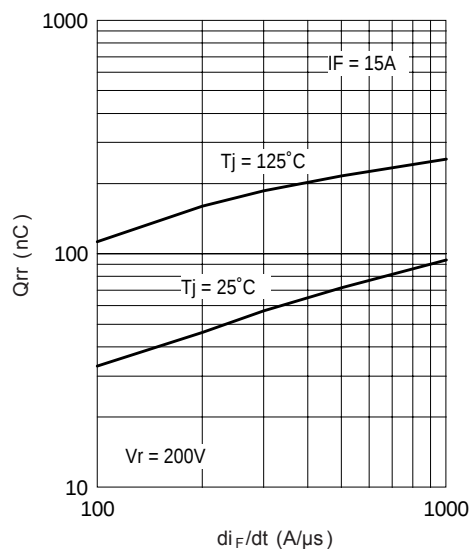


Fig. 8 - Typical Stored Charge vs. di_F/dt

① Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_{R1} (1 - D)$; $I_{R1} @ V_{R1}$ = rated V_R

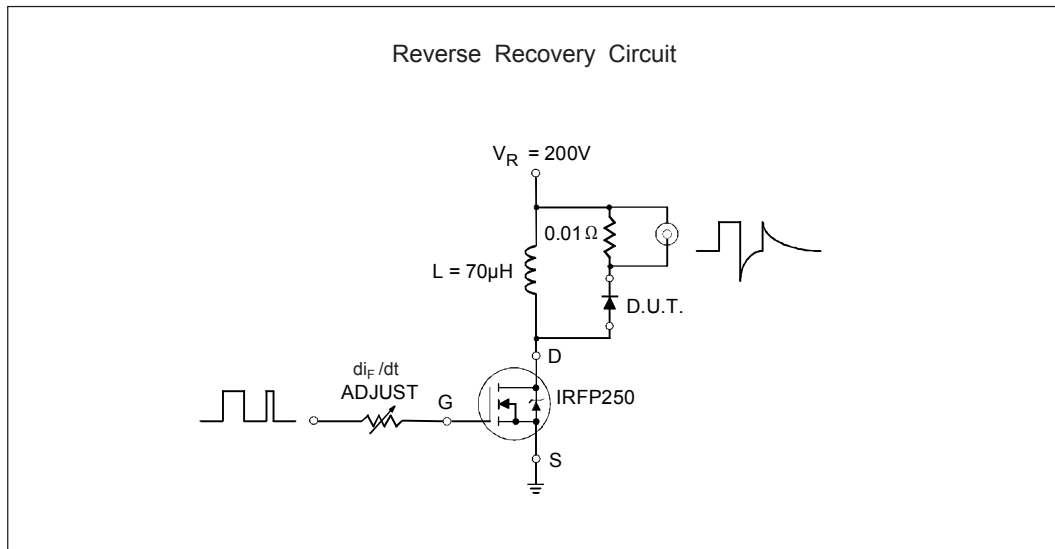


Fig. 9- Reverse Recovery Parameter Test Circuit

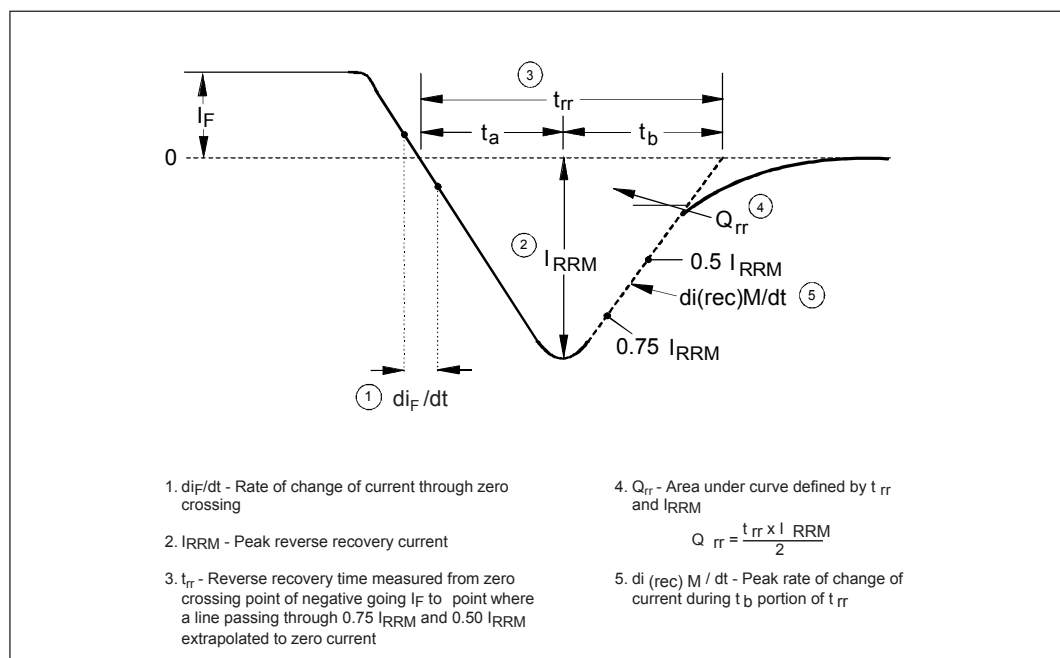
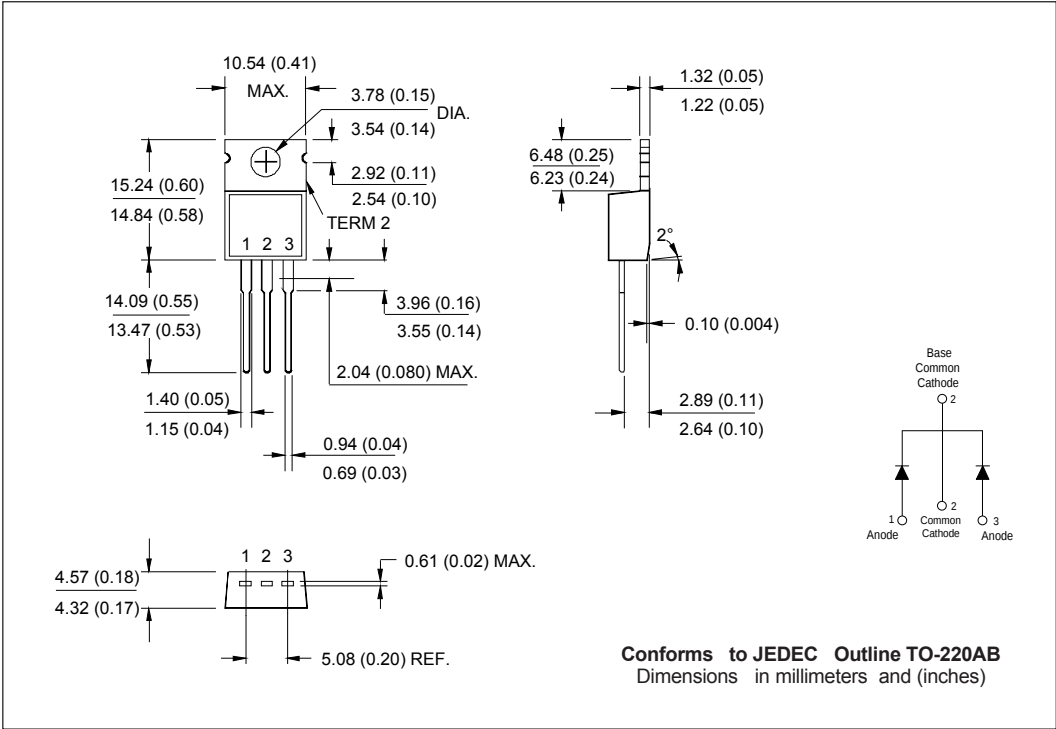


Fig. 10 - Reverse Recovery Waveform and Definitions

Outline Table



Ordering Information Table

Device Code				
30	C	T	H	03
1	2	3	4	5
1	- Current Rating (30 = 30A)			
2	- C = Common Cathode			
3	- T = TO-220			
4	- H = HyperFast Recovery			
5	- Voltage Rating (03 = 300V)			

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 08/03